

WHAT IS THE REASON FOR DIFFERENT MAGNETIC PROPERTIES OF THE COMPOUNDS TmRu_2Si_2 AND YbRu_2Si_2 AMONG THE RRu_2Si_2 COMPOUNDS?*

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Experimental observations and theoretical analysis allow for understanding of the extremely anisotropic magnetic properties of compounds ErRu_2Si_2 and PrRu_2Si_2 . The presented here calculations for TmRu_2Si_2 and YbRu_2Si_2 reveal that their properties are quite different from those of the Er and Pr compounds. We have found that a low-temperature ordering of YbRu_2Si_2 and a weak ferromagnetism ($T_C \approx 1\text{K}$) of TmRu_2Si_2 can be obtained by using crystal-field parameters directly recalculated from ErRu_2Si_2 and PrRu_2Si_2 . Moreover, an effect of the temperature-dependent rotation of the easy magnetic axis in YbRu_2Si_2 is predicted.

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1. Introduction

Magnetic properties of monocrystalline ternary compounds RRu_2Si_2 ($\text{R} = \text{Pr}, \text{Nd}, \text{Tb}, \text{Dy}, \text{Ho}, \text{Er}$) are strongly anisotropic. Calculations of magnetocrystalline anisotropy for ErRu_2Si_2 [1] and PrRu_2Si_2 [2] were performed. A well-defined direction of the magnetic easy axis for these compounds was not changing in the whole temperature range and the magnetocrystalline anisotropy was significant. The direction and the value of the anisotropy field in case of PrRu_2Si_2 and ErRu_2Si_2 depends on the crystal field (CEF) that has similar values of the coefficients A_n^m for both compounds, but yields the different directions of easy axes [1–3]. In this situation the results of the similar calculations for TmRu_2Si_2 and YbRu_2Si_2 are surprising. We have treated Tm^{3+} and Yb^{3+} ions in the same manner as the Er^{3+} and Pr^{3+}

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ions, but the obtained results are quite different from those for the Er and Pr compounds. Our calculations provide the answer to the question: why YbRu₂Si₂ and TmRu₂Si₂ have such low temperature of ordering (Ordering temperature YbRu₂Si₂ is not found and TmRu₂Si₂ exhibits a weak ferromagnetism ($T_C \approx 1$ K) [6]. We have established that these properties can be evoked by CEF parameters directly recalculated from ErRu₂Si₂ and PrRu₂Si₂. Moreover, an effect of the temperature-dependent rotation of the easy magnetic axis in YbRu₂Si₂ is predicted.

2. Outline of theory

Our approach bases on the crystal fields model, that points out that f atoms partially preserve their atomic properties even becoming the full part of a solid [8]. We have attributed the magnetic properties of TmRu₂Si₂ and YbRu₂Si₂ to be predominantly due to the $4f^{12}$ and $4f^{13}$ electronic system of the Tm³⁺ and Yb³⁺ ions respectively [4]. The used method is based on according to the local symmetry of the surroundings of the R ions, which leads to the tetragonal CEF+Zeeman Hamiltonian:

$$H_{\text{tetra}} = B_2^0 \hat{O}_2^0(J, J_z) + B_4^0 \hat{O}_4^0(J, J_z) + B_4^4 \hat{O}_4^4(J, J_z) \\ + B_6^0 \hat{O}_6^0(J, J_z) + B_6^4 \hat{O}_6^4(J, J_z) + g_J \mu_B \mathbf{J} \cdot \mathbf{B}_{\text{ext}},$$

where B_n^m are CEF parameters, \hat{O}_n^m are Stevens operators, g_J is Landé factor, \mathbf{B}_{ext} is the external magnetic field. The values of total momentum quantum numbers \mathbf{J} of the R ions are 6 and $\frac{7}{2}$ for Tm³⁺ and Yb³⁺ ions, respectively. The details of the calculations of the magnetic properties are explained in Ref. [9]. The main idea of the theoretical estimation of the properties of the considered compounds is possibility of the selection of the CEF parameters for the YbRu₂Si₂ and TmRu₂Si₂ according to parameters established for ErRu₂Si₂ and PrRu₂Si₂ [1–3]. Direct recalculation from it base at the subtraction of the local-potentials coefficients A_n^m according to the formula:

$$B_n^m = A_n^m \langle r_{4f}^n \rangle \theta_n,$$

where the $\langle r_{4f}^n \rangle$ is average of n -power of radius of the $4f$ shell and θ_n are the scaling parameter, Stevens coefficients, dependent on the number of $4f$ electrons. The values of θ_n can be found in [7]. Coefficients A_n^m carry information of the potential of the local environment of rare ions in the crystal structure. We assume that proper values of A_n^m should be similar for the whole family of compounds RRu₂Si₂.

3. Results for TmRu₂Si₂

The main properties of 3 lowest lying states are collected in Table I. Independently of the used set of parameters (recalculated from ErRu₂Si₂ or PrRu₂Si₂), practically the same energy structure has been found: the

TABLE I

Sets of CEF parameters for TmRu₂Si₂ and YbRu₂Si₂ together with the magnetic characteristics of 3 lowest states. g.s. denotes the ground state, 1st, 2nd e.s. denote the first and second excited states, $\langle J_x \rangle$ and $\langle J_z \rangle$ are the expectation values of x and z components of the total angular momentum J ; **K-doublet** and **nk-doublet** denote Kramers and non-Kramers doublet, δ_1 and δ_2 are energies of the excited states with respect to the ground state, $m(B)$ is the magnetic moment at 1 K in the external field B .

		PrRu ₂ Si ₂		ErRu ₂ Si ₂	
n	m	B_n^m	A_n^m	B_n^m	A_n^m
2	0	- 22.0 K	+867 K/a ₀ ⁻²	+ 1.6 K	+ 870 K/a ₀ ⁻²
4	0	+ 220 mK	-88.2 K/a ₀ ⁻⁴	- 5.0 mK	- 88 K/a ₀ ⁻⁴
6	0	- 12 mK	-11 K/a ₀ ⁻⁶	- 5 μK	-0.5 K/a ₀ ⁻⁶
4	4	+ 200 mK	- 80.2 K/a ₀ ⁻⁴	- 4.5 mK	- 80 K/a ₀ ⁻⁴
6	4	-45 mK	- 39 K/a ₀ ⁻⁶	- 0.52 mK	- 50 K/a ₀ ⁻⁶
		Recalculated parameters	Properties	Recalculated parameters	Properties
TmRu ₂ Si ₂		$B_2^0 = +6.0$ K	easy axis: [1 0 0] $m_z(6T) = 0.00 \mu_B/\text{ion}$ $m_x(6T) = 2.8 \mu_B/\text{ion}$	$B_2^0 = +6.0$ K	easy axis: [1 0 0] $m_z(6T) = 0.01 \mu_B/\text{ion}$ $m_x(6T) = 4.5 \mu_B/\text{ion}$
		$B_4^0 = -16.9$ mK	g.s.- Singlet $\langle J_z \rangle = \langle J_x \rangle = 0.00$.	$B_4^0 = -16.9$ mK	g.s.- Singlet $\langle J_z \rangle = \langle J_x \rangle = 0.00$.
		$B_6^0 = +256$ μK	1st e.s.- n-K doublet $\delta_1 = 74$ K (<i>INS visible</i>) $\langle J_z \rangle = \pm 0.85$, $\langle J_x \rangle = 0.00$.	$B_6^0 = +12$ μK	1st e.s.- n-K doublet $\delta_1 = 33.8$ K (<i>INS visible</i>) $\langle J_z \rangle = \pm 0.68$, $\langle J_x \rangle = 0.00$.
		$B_4^4 = -15.4$ mK	2nd e.s.- singlet $\delta_2 = 222$ K (<i>INS visible</i>) $\langle J_z \rangle = \langle J_x \rangle = 0.00$.	$B_4^4 = -15.4$ mK	2nd e.s.- singlet $\delta_2 = 98.7$ K (<i>INS visible</i>) $\langle J_z \rangle = \langle J_x \rangle = 0.00$.
		$B_6^4 = +0.96$ mK		$B_6^4 = +1.27$ mK	
YbRu ₂ Si ₂		$B_2^0 = +18.1$ K	easy axis: [? ? ?] $m_z(6T) = 1.64 \mu_B/\text{ion}$ $m_x(6T) = 0.94 \mu_B/\text{ion}$	$B_2^0 = +18.4$ K	easy axis: [? ? ?] $m_z(6T) = 1.45 \mu_B/\text{ion}$ $m_x(6T) = 1.86 \mu_B/\text{ion}$
		$B_4^0 = +166$ mK	$m_z(30T) = 1.67 \mu_B/\text{ion}$ $m_x(30T) = 1.78 \mu_B/\text{ion}$	$B_4^0 = +167$ mK	g.s.- K-doublet $\langle J_z \rangle = \pm 1.39$, $\langle J_x \rangle = \pm 1.05$.
		$B_6^0 = -6.12$ mK	g.s.- K-doublet $\langle J_z \rangle = \pm 1.63$, $\langle J_x \rangle = \pm 0.55$.	$B_6^0 = -0.292$ mK	1st e.s.- K-doublet $\delta_1 = 24.9$ K (<i>INS visible</i>) $\langle J_z \rangle = \pm 0.57$, $\langle J_x \rangle = \pm 2.26$.
		$B_4^4 = +151$ mK	1st e.s.- K-doublet $\delta_1 = 123$ K (<i>INS visible</i>) $\langle J_z \rangle = \pm 0.57$, $\langle J_x \rangle = \pm 2.28$.	$B_4^4 = +150$ mK	2nd e.s.- K-doublet $\delta_2 = 146.4$ K (<i>INS visible</i>) $\langle J_z \rangle = \pm 2.53$, $\langle J_x \rangle = \pm 1.02$.
		$B_6^4 = -22.9$ mK	2nd e.s.- K-doublet $\delta_2 = 235$ K (<i>INS visible</i>) $\langle J_z \rangle = \pm 2.77$, $\langle J_x \rangle = \pm 2.29$.	$B_6^4 = -30.4$ mK	

singlet ground state and a non-Kramers doublet as the 1st excited state. Such configuration is hard to polarize magnetically by the mechanism found in PrRu₂Si₂ [1]. In the case of TmRu₂Si₂ the external field of 6T parallel to the local x-axis (easy axis) induces only 0.4 of the Tm³⁺ full moment of 7μ_B. Thus, according to us, this inactive singlet ground state is the reason for the low-temperature ordering of TmRu₂Si₂.

4. Results for YbRu₂Si₂

For the Yb³⁺ ion the recalculated CEF parameters yield the energy scheme with intriguing properties. For both sets of CEF parameters the 1st excited Kramers doublet has the opposite direction of the magnetic moment than the Kramers-doublet ground state. Moreover, the moment of the excited state is much larger than that in the ground state (Fig. 1). Such a situation causes rotation of the easy magnetic axis with the increasing temperature from the direction [1 0 0] (or [0 1 0]) to [0 0 1] when the excited state becomes populated. The computer simulation of the influence of the external magnetic field reveals the crossing of the magnetization curves for different directions. It means that the easy magnetic axis changes with the field. The rotation field B_R depends on the chosen set of the parameters (recalculated from ErRu₂Si₂ or PrRu₂Si₂). Such rotation of the easy magnetic axis of the Yb³⁺ ion prevents, the formation of the long-range magnetic order in YbRu₂Si₂.

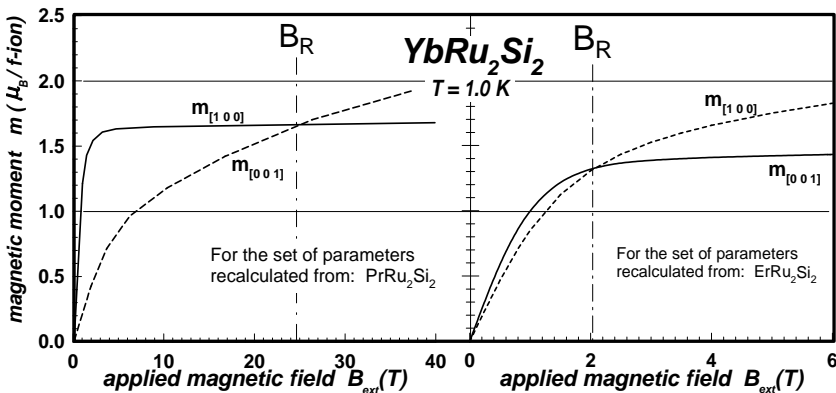


Fig. 1. Magnetization curves of YbRu₂Si₂ in applied fields along 2 main directions. B_R is the rotation field.

5. Conclusions

Magnetic properties of TmRu_2Si_2 and YbRu_2Si_2 have been discussed. Our results reveal the reason for the extremely low ordering temperature of these compounds. The isolated singlet for TmRu_2Si_2 and the rotating easy axis in YbRu_2Si_2 could be studied further, both theoretically and experimentally. This work is only the starting point towards the understanding these compounds. The final evaluation of the fine electronic structure of these compounds will be possible once the inelastic neutron scattering for TmRu_2Si_2 and YbRu_2Si_2 are carried out.

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REFERENCES

- [1] R. Michalski, Z. Ropka, R.J. Radwanski, *J. Phys.: Condens. Matter* **12**, 7609 (2000).
- [2] R. Michalski, Z. Ropka, R.J. Radwanski, *Physica B* **312–313**, 858 (2002).
- [3] R. Michalski, R.J. Radwanski, Z. Ropka, *Acta Phys. Pol. B* **31**, 3079 (2000).
- [4] K. Hiebl, C. Horvath, P. Rogl, M.J. Sienko, *J. Magn. Magn. Mater.* **37**, 287 (1983).
- [5] K. Muramoto, T. Takeuchi, T. Taniguchi, Y. Miyako, *Physica B* **206–207**, 519 (1995).
- [6] <http://www.css-physics.edu.pl/download.html>
- [7] M.T. Hutchings, *Solid State Phys.* **16**, 227 (1964).
- [8] R.J. Radwanski, Z. Ropka, *cond-mat/0010081*.
- [9] R.J. Radwanski, N.H. Kim-Ngan, F.E. Kayzel, J.J.M. Franse, D. Gignoux, D. Schmitt, F.Y. Zhang, *J. Phys.: Condens. Matter* **4**, 8853 (1992).